

In the claims:

Please amend claim 5 as follows:

5. (Amended) An active matrix device comprising:

a first substrate;
a second substrate opposed to said first substrate;
a thin film transistor formed over said first substrate,
said thin film transistor comprising an active layer;

an interlayer insulating film formed over the thin film
transistor;

at least two source lines formed over said thin film
transistor;

at least two gate lines intersecting to said two source
lines respectively;

a metal interconnection connected to said active layer
through a first contact hole formed in the interlayer insulating
film;

a pixel by said two source lines and said two gate lines;

a light blocking film formed over said thin film
transistor;

a capacitor formed between a portion of said metal
interconnection and said light blocking film with a second
interlayer insulating film interposed therebetween;

a pixel electrode formed over said light blocking film;
and

liquid crystal molecules arranged between said first
substrate and said second substrate, said liquid crystal molecules
oriented by rubbing in one direction from one corner of said
pixel,

wherein said portion is apart from the contact hole, and
wherein a disclination of said liquid crystal molecules is
occurred in a region comprising said one corner, and wherein said
region and said capacitor overlaps with each other.